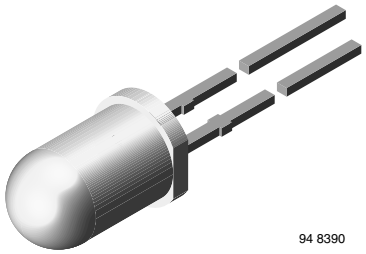
Silicon PIN Photodiode, RoHS Compliant



FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Leads with stand-off
- Radiant sensitive area (in mm^2): 0.78
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- High bandwidth: 250 MHz at V_R = 12 V
- Fast response times
- Angle of half sensitivity: φ = ± 20°
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

Pb-free

e4

RoHS COMPLIANT

DESCRIPTION

BPV10 is a PIN photodiode with high speed and high radiant sensitivity in clear, T-1¾ plastic package. It is sensitive to visible and near infrared radiation.

APPLICATIONS

- High speed photo detector

PRODUCT SUMMARY			
COMPONENT	**I_{ra} (mA)**	**φ (deg)**	**$\lambda_{0.1}$ (nm)**
BPV10	70	± 20	380 to 1100

Note

Test condition see table “Basic Characteristics”

ORDERING INFORMATION			
ORDERING CODE	**PACKAGING**	**REMARKS**	**PACKAGE FORM**
BPV10	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Reverse voltage		V_R	10	V
Power dissipation	$T_{amb} \leq 25$ °C	P_V	215	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from body	T_{sd}	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm^2	R_{thJA}	350	K/W

Note

T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 50 mA	V_F		1.0	1.3	V
Breakdown voltage	I_R = 100 µA, E = 0	$V_{(BR)}$	60			V
Reverse dark current	V_R = 20 V, E = 0	I_{ro}		1	5	nA
Diode capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_D		11		pF
	V_R = 5 V, f = 1 MHz, E = 0	C_D		3.8		pF
Open circuit voltage	E_A = 1 klx	V_O		480		mV
	E_e = 1 mW/cm², λ = 950 nm	V_O		450		mV
Short circuit current	E_A = 1 klx	I_K		80		µA
	E_e = 1 mW/cm², λ = 950 nm	I_K		65		µA
Reverse light current	E_A = 1 klx, V_R = 5 V	I_{ra}		85		µA
	E_e = 1 mW/cm², λ = 950 nm, V_R = 5 V	I_{ra}	38	70		µA
Absolute spectral sensitivity	V_R = 5 V, λ = 950 nm	s(λ)		0.55		A/W
Angle of half sensitivity		φ		± 20		deg
Wavelength of peak sensitivity		λ_p		920		nm
Range of spectral bandwidth		$\lambda_{0.1}$		380 to 1100		nm
Quantum efficiency	λ = 950 nm	η		72		%
Noise equivalent power	V_R = 20 V, λ = 950 nm	NEP		3×10^{-14}		W/√Hz
Detectivity	V_R = 20 V, λ = 950 nm	D		3×10^{12}		cm√Hz/W
Rise time	V_R = 50 V, R_L = 50 Ω, λ = 820 nm	t_r		2.5		ns
Fall time	V_R = 50 V, R_L = 50 Ω, λ = 820 nm	t_f		2.5		ns

Note

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BASIC CHARACTERISTICS

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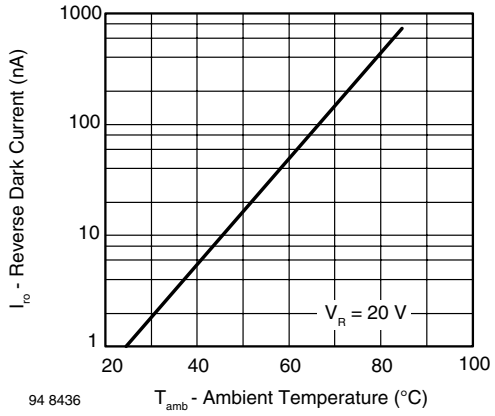


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

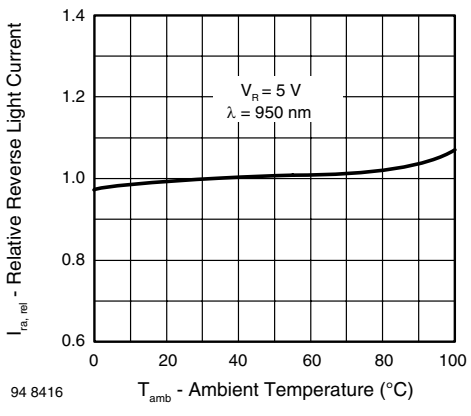


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

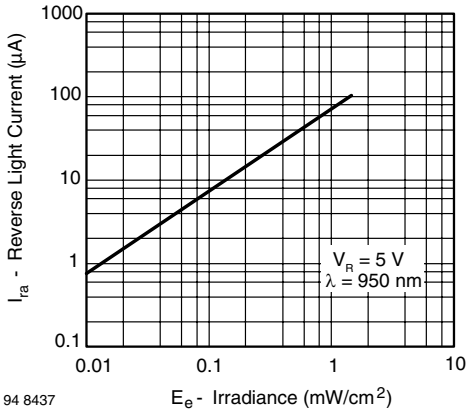


Fig. 3 - Reverse Light Current vs. Irradiance

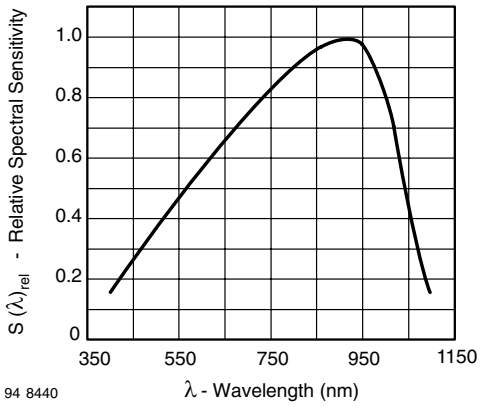


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

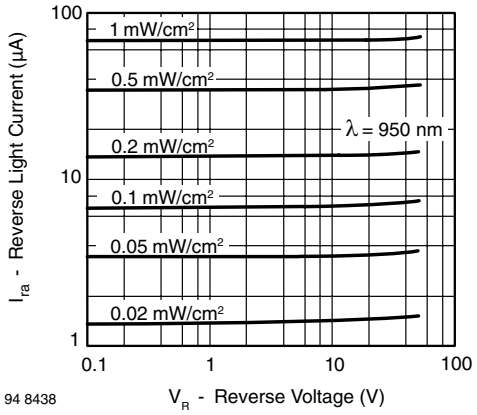


Fig. 4 - Reverse Light Current vs. Reverse Voltage

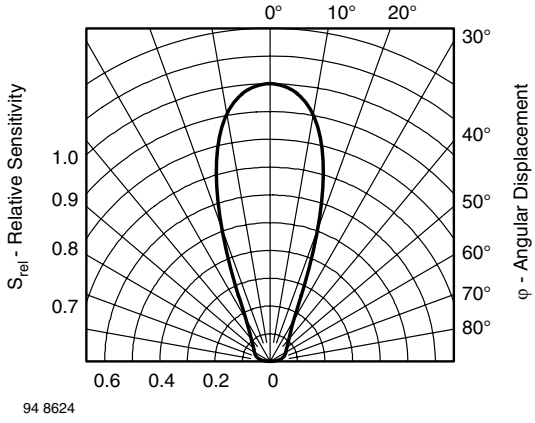


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

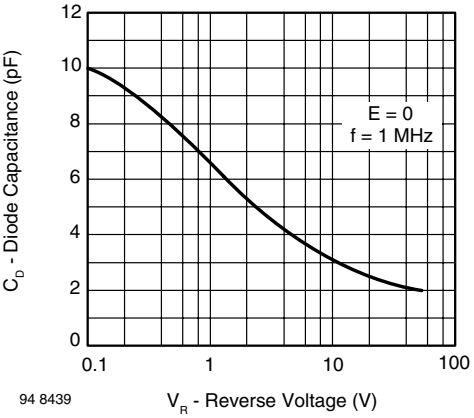
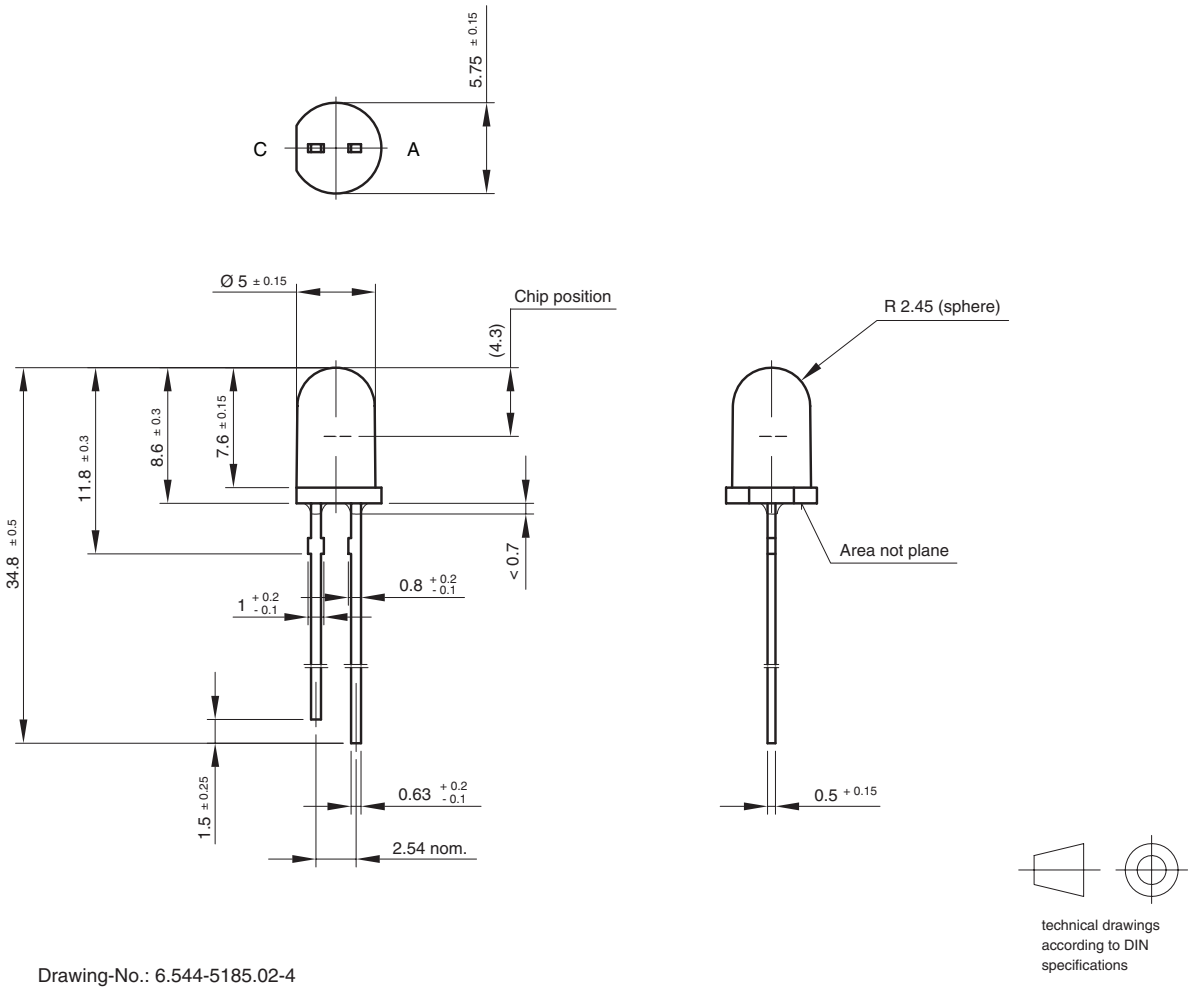


Fig. 5 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters



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